



[Home](#) > [Temperature](#) > [Monitors](#) > Model 211

Model 211 Temperature Monitor

Product Overview

Tech Specs

Ordering Information

Downloads



| Thermometry | |
|---------------------------------|---|
| Number of Inputs | One. |
| Measurement Type | Four-lead differential. |
| Excitation | Constant current, 10 μ A or 1mA |
| Isolation | Measurement is not isolated from chassis ground |
| Supported Sensors | Diodes-Silicon, GaAlAs RTDs-100 Ω Platinum, 1000W Platinum, Cernox TM , Carbon Glass TM , ROX TM |
| Sensor Type Selection | Front panel selectable |
| Standard Curves | DT-470, DT-670, CTI Curve C, PT-100, PT-1000 |
| Input Connector | DB-25 |
| A/D Resolution | 24 bit |
| Input Accuracy | Sensor dependent (see performance chart) |
| Measurement Resolution | Sensor dependent (see performance chart) |
| Maximum Update Rate | 7 readings per second |
| User Curve | One 200-point CalCurve or user curve in non-volatile memory |
| Front Panel | |
| Display Type | 5 digit LED |
| Display Units | $^{\circ}$ C, $^{\circ}$ F, V, and Ω |
| Display Update Rate | Twice per second |
| Temperature Display Resolution | 0.001 $^{\circ}$ from 0 $^{\circ}$ - 99.999 $^{\circ}$, 0.01 $^{\circ}$ from 100 $^{\circ}$ - 999.99 $^{\circ}$, 0.1 $^{\circ}$ above 1000 $^{\circ}$ |
| Sensor Units Display Resolution | Sensor dependent to 5 digits |
| Display Annunciator | K, $^{\circ}$ C, $^{\circ}$ F, V/ Ω |
| Interface | |
| Serial Interface | RS-232C |
| BAUD | 9600 |
| Update rate | 7 readings per second |
| Connector | DE-9 |
| Alarms | |
| Settings | High setpoint, Low setpoint, Dead band, Latching or Non-latching |
| Actuators | Display message, relays |
| Relays | |
| Contacts | Normally Open (NO), Normally Closed (NC), and Common (C) |
| Contact Rating | 30VDC at 1A |
| Operation | Operate with high and low alarms |
| Connector | DB-25 |
| Analog Output | |
| Settings | Voltage or current, scale |
| Update Rate | 7 readings per second |

| | Voltage | Current |
|---------------------------|--|------------------------------|
| Range | 0-10 V | 4-20 mA |
| Accuracy | ±1.25 mV | ±2.5 µA |
| Resolution | 0.3 mV | 0.6 µA |
| Min Load | 500 W | N/A |
| Compliance | | 10 V |
| | | |
| Scales: | Temperature | Sensor Units (Fixed by type) |
| | 0-20 K | Diodes: 1 V=1 V |
| | 0-100 K | 100 Ω Platinum: 1 V=100 Ω |
| | 0-200 K | 1000 Ω Platinum: 1 V=1000 Ω |
| | 0-325 K | NTC Resistor: 1 V=1000 Ω |
| | 0-475 K | |
| | 0-1000 K | |
| | | |
| | | |
| Connector: | DB-25 | |
| General | | |
| Ambient Temperature Range | 15 to 35 °C at rated accuracy, 10-40 °C at reduced accuracy | |
| Power Requirements | Regulated +5 VDC@300 mA, +15 VDC@75 mA, -15 VDC@15 mA, 5 pin DIN | |
| Size | 96 mm W x 48 mm H x 166 mm D | |
| Mounting | Panel mount into 91 mm W x 44 mm H cutout | |
| Weight | 0.65 kg (1.5 lbs) | |
| Approval | CE Mark (consult factory) | |
| | | |
| | | |
| | | |

| 211 Sensor Input Performance Chart | | | | | |
|---|--|---|---|---|--|
| Sensor Type | Silicon Diode | GaAlAs Diode | 100W Platinum RTD 500 W Full Scale | Ruthenium Oxide RTD | Cernox™ RTD |
| Temperature coefficient | Negative | Negative | Positive | Negative | Negative |
| Sensor units | Volts(V) | Volts(V) | Ohms(Ω) | Ohms(Ω) | Ohms(Ω) |
| Input range | 0 - 2.5 V | 0 - 7.5 V | 0 - 500 Ω^2 | 0-7500 Ω | 0-7500 Ω |
| Sensor excitation (Constant Current) | 10 μ A \pm 0.01% | 10 μ A \pm 0.01% | 1 mA \pm 0.3% | 10 μ A \pm 0.01% | 10 μ A \pm 0.01% |
| Display resolution (Sensor Units) | 100 μ V | 100 μ V | 10 m Ω | 100 m Ω | 100 m Ω |
| Example LSCI sensor | DT-670-SD with 104H Calibration | TG-120SD with 1.4H Cal. | PT-103 with 14J Calibration | Rx-102A-AA with 0.3E Calibration | CX-1050-SD with 4L Calibration |
| Temperature range | 1.4 - 500 K | 1.4 - 500 K | 30 - 800 K | 0.25 - 40 K | 3.5 - 400 K |
| Standard Curve | Curve 670 | Requires Calibration | DIN 43760 | LSCI Curve RX-102A | Requires Calibration |
| Typical sensor sensitivity | -30 mV/K at 4.2 K -1.9 mV/K at 77 K -2.4 mV/K at 300 K -2.2 mV/K at 475 K | -180 mV/K at 10 K -1.25 mV/K at 77 K -2.75 mV/K at 300 K 10 mV/K at 475 K | 0.19 Ω /K at 30 K 0.42 Ω /K at 77 K 0.39 Ω /K at 300 K 0.35 Ω /K at 675 K 0.35 Ω /K at 800 K | -80 Ω /K at 4.2 K -4 Ω /K at 20 K -1.06 Ω /K at 40 K | -770 Ω /K at 4.2 K -1.5 Ω /K at 77 K -0.1 Ω /K at 300 K |
| Mesaurement resolution (Sensor units) | 20 μ V | 20 μ V | 2 m Ω | 50 m Ω | 50 m Ω |
| Temperature equivalence | 1 mK at 10 K 16 mK at 77 K 10 mK at 300 K 10 mK at 475 K | 1 mK at 10 K 16 mK at 77 K 10 mK at 300 K 10 mK at 475 K | 10.6 mK at 30 K 10 mK at 77 K 10 mK at 300 K 10 mK at 675 K 10 mK at 800 K | 1 mK at 4.2 K 12.5 mK at 20 K 47 mK at 40 K | 1 mK at 4.2 K 33.3 mK at 77 K 500 mK at 300 K |
| Electronic accuracy (Sensor units) | \pm 160 μ V \pm 0.01% RDG | \pm 160 μ V \pm 0.02% RDG | \pm 0.004 Ω \pm 0.02% RDG | \pm 0.10 Ω \pm 0.04% RDG | \pm 0.01 Ω \pm 0.04% RDG |
| Temperature equivalence | \pm 11 mK at 4.2 K \pm 138 mK at 77 K \pm 88 mK at 300 K \pm 77 mK at 475 K | \pm 6 mK at 10 K \pm 300 mK at 77 K \pm 150 mK at 300 K \pm 110 mK at 475 K | \pm 25 mK at 30 K \pm 18 mK at 77 K \pm 70 mK at 300 K \pm 162 mK at 675 K \pm 187 mK at 800 K | \pm 8.1 mK at 4.2 K \pm 134 mK at 20 K \pm 491 mK at 40 K | \pm 1 mK at 4.2 K \pm 88 mK at 77 K \pm 1.144 mK at 300 K |
| Temperature accuracy including electronic accuracy, CalCurve™ and calibrated sensor | \pm 31 mK at 4.2 K \pm 193 mK at 77 K \pm 138 mK at 300 K \pm 177 mK at 475 K | \pm 21 mK at 10 K \pm 390 mK at 77 K \pm 140 mK at 300 K \pm 210 mK at 475 K | \pm 45 mK at 30 K \pm 38 mK at 77 K \pm 105 mK at 300 K \pm 262 mK at 675 K \pm 287 mK at 800 K | \pm 24.1 mK at 4.2 K \pm 238 mK at 20 K \pm 705 mK at 40 K | \pm 9 mK at 4.2 K \pm 138 mK at 77 K \pm 1.284 mK at 300 K |
| Magnetic Field use | Recommended for T \geq 60K & B \leq 3T | Recommended for T > 4.2 K & B < 5 T | Recommended for T > 40 K & B \leq 2.5 T | Recommended for T > 2 K & B \leq 10 T | Recommended for T > 2 K & B \leq 19 T |
| ¹ Specified accuracy includes no effects of thermal EMF voltages. An error of 3 mW results from each 1 μ V of thermal EMF voltage. In well-designed systems thermal EMF voltage should be less than 10 μ V | | | | | |
| ² 0-500 W and 250 W input range is also available on the Model 211 | | | | | |

[Top](#)

[Home](#) | [Temperature](#) | [Magnetics](#) | [Systems](#) | [Order Now & Pricing](#) | [Contact Us](#) | [What's New](#) | [Site Map](#)

Copyright 2002 Lake Shore Cryotronics, Inc.